

MS2473

MS2473 Information

Container, com	Part Number Manufacturer Category Description Package	MS2473 Microsemi Corporation Discrete Semiconductor Products Transistors - Bipolar (BJT) - RF TRANS RF BIPO 2300W 46A M112 M112 For the pricing/inventory/lead time, please contact	
For Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

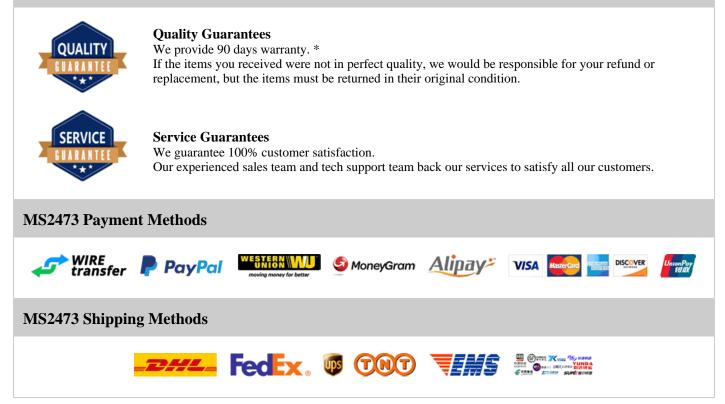
Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



MS2473 Specifications

Manufacturer Part Number	MS2473
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	M112
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	65V
Frequency - Transition	1.09GHz
Noise Figure (dB Typ @ f)	-
Gain	6dB
Power - Max	2300W
DC Current Gain (hFE) (Min) @ Ic, Vce	5 @ 1A, 5V
Current - Collector (Ic) (Max)	46A
Operating Temperature	200°C (TJ)
Mounting Type	Chassis Mount
Package / Case	M112
Supplier Device Package	M112
	Report errors?

MS2473 Guarantees



If you have any question about MS2473, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com